

SANYO**LB1886V****Three-Phase Brushless Motor Driver****Overview**

The LB1886V is a three-phase brushless motor driver IC that is optimal for capstan and drum motor drive in camcorders and other VCR products and for motor drive in digital audio products.

Features

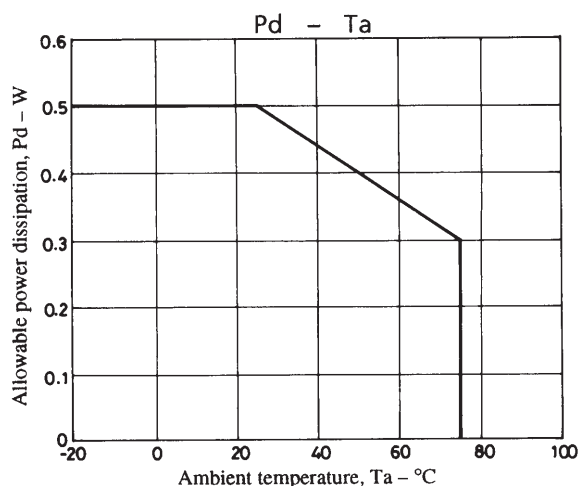
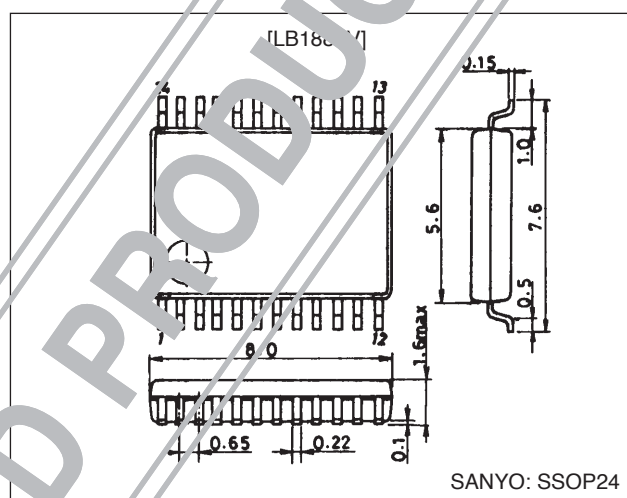
- 120° voltage linear drive scheme
- Motor voltage control based speed control provides reduced power (and thus is optimal for use in portable equipment)
- Built-in torque ripple compensation filter
- Soft switching scheme requires a smaller external capacitance (thus chip capacitors can be used)
- Built-in thermal shutdown circuit
- Built-in FG amplifier

Specifications**Absolute Maximum Ratings at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	$V_{CC1\ max}$		7	V
Maximum supply voltage 2	$V_{CC2\ max}$		12	V
Maximum supply voltage 3	$V_S\ max$		V_{CC2}	V
Applied output voltage	$V_o\ max$		$V_S + 2$	V
Applied input voltage	$V_i\ max$	All input pins	V_{CC1}	V
Output current	$I_o\ max$		1.0	A
Allowable power dissipation	$P_d\ max$		0.5	W
Operating temperature	T_{op}		-20 to +75	°C
Storage temperature	T_{stg}		-55 to +150	°C

Package Dimensions

unit: mm

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Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V _{CC1}	V _{CC1} ≤ V _{CC2}	4.0 to 6.0	V
Supply voltage 2	V _{CC2}		4 to 10	V
Supply voltage 3	V _S		up to V _{CC2}	V

Electrical Characteristics at Ta = 25°C, V_{CC1} = 5 V, V_{CC2} = 7 V, V_S = 3 V

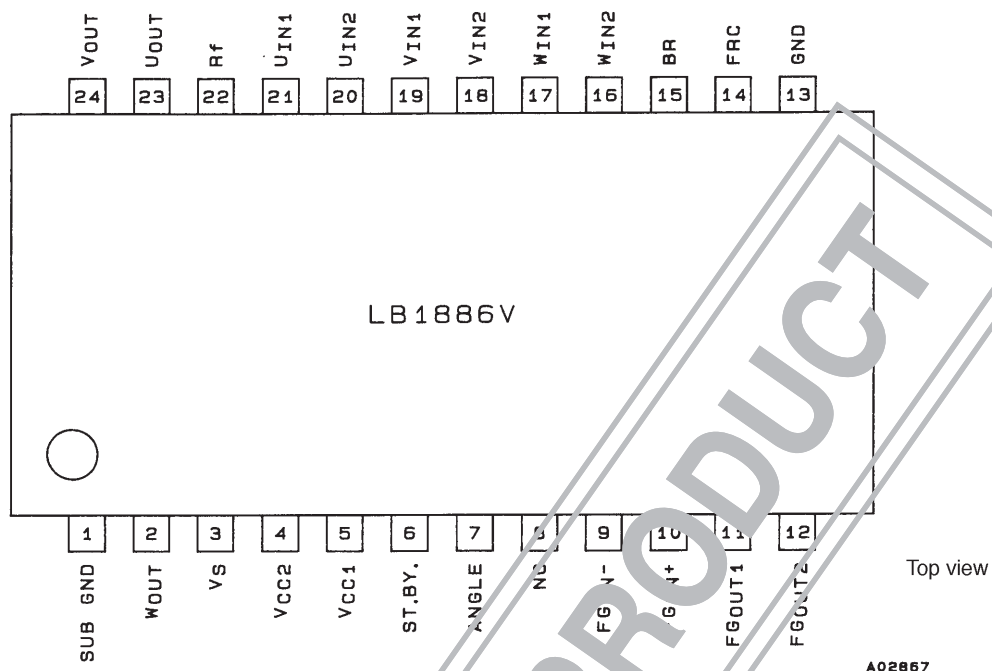
Parameter	Symbol	Conditions	min	typ	max	Unit
Current drain 1	I _{CC1}	V _{BR} = 5 V		3.0	5.0	mA
Current drain 2	I _{CC2}	V _{BR} = 5 V		6	10.0	mA
Current drain 3	I _S	V _{BR} = 5 V, R _L = ∞			5.0	mA
Quiescent current 1	I _{CCOQ}	V _{STBY} = 0 V			100	μA
Quiescent current 2	I _{SOQ}	V _{STBY} = 0 V, R _L = ∞			150	μA
Output saturation voltage	V _{O (sat)}	I _{OUT} = 0.6 A, sink + source			1.7	V
Output transistor breakdown voltage	V _{O (sus)}	I _{OUT} = 20 mA, *2				V
Quiescent voltage	V _{OQ}	V _{BR} = 5 V	1.45	1.55	1.65	V
Hall amplifier input offset voltage	V _{H offset}	*2	-5		+5	mV
Hall amplifier common mode input voltage range	V _{HCOM}		1.4		2.8	V
Hall I/O voltage gain	G _{VHO}	R _{angle} = 8.2 kΩ	34.5	37.5	40.5	dB
Brake pin high level voltage	V _{BRH}		2.0			V
Brake pin low level voltage	V _{BRL}				0.8	V
Brake pin input current	I _{BRIN}				120	μA
Brake pin leakage current	I _{BR leak}				-30	μA
FRC pin high level voltage	V _{FRCH}		2.8			μA
FRC pin low level voltage	V _{FRCL}				1.2	μA
FRC pin input current	I _{FRCL}				100	μA
FRC pin leakage current	I _{FRC leak}				-30	μA
Upper side residual voltage	V _{XH}	I _{OUT} = 100 mA, V _{CC2} = 6 V, V _S = 2 V	0.285		0.455	V
Lower side residual voltage	V _{XL}	I _{OUT} = 100 mA, V _{CC2} = 6 V, V _S = 2 V	0.350		0.440	V
Residual voltage inflection point	V _{SΔVX}	I _{OUT} = 100 mA, V _{CC2} = 6 V, *2		0.9		V
Overlap	OL	V _{CC2} = 6 V, V _S = 3 V, R _L = 100 Ω (Y)	69	79	89	%
Overlap vertical delta	ΔOL	V _{CC2} = 6 V, V _S = 3 V, R _L = 100 Ω (Y)	-10	0	+10	%
Standby on voltage	V _{STBYL}		-0.2		+0.8	V
Standby off voltage	V _{STBYH}		2		5	V
Standby pin bias current	I _{STBY}				100	μA
Thermal protection circuit operating temperature	T _{PS}		150	180	210	°C
Thermal protection circuit hysteresis	T _{PTSD}	*2		15		°C
[FG Amplifier]						
FG amplifier input offset voltage	V _{FG offset}		-8		+8	mV
Open loop voltage gain	A _{VFG}	f = 10 kHz		43		dB
Source output saturation voltage	V _{FG OU}	I _O = -2 mA	3.7			V
Sink output saturation voltage	V _{FG OD}	I _O = 2 mA			1.3	V
Common mode signal rejection ratio	CMRR	*2		80		dB
FG amplifier common mode input voltage range	V _{FG CH}		0		+3.5	V
Phase margin	φM	*2		20		deg
Schmitt amplifier threshold voltage	V _{FSG SH}	V _{FGIN} * = 2.5 V, when V _{FGOUT2} goes from high to low	2.45	2.50	2.55	V
Schmitt amplifier hysteresis	V _{FSG HIS}	V _{FGIN} * = 2.5 V	20	40	60	mV

Note: 1. The IC goes to the standby state when the standby pin is open.

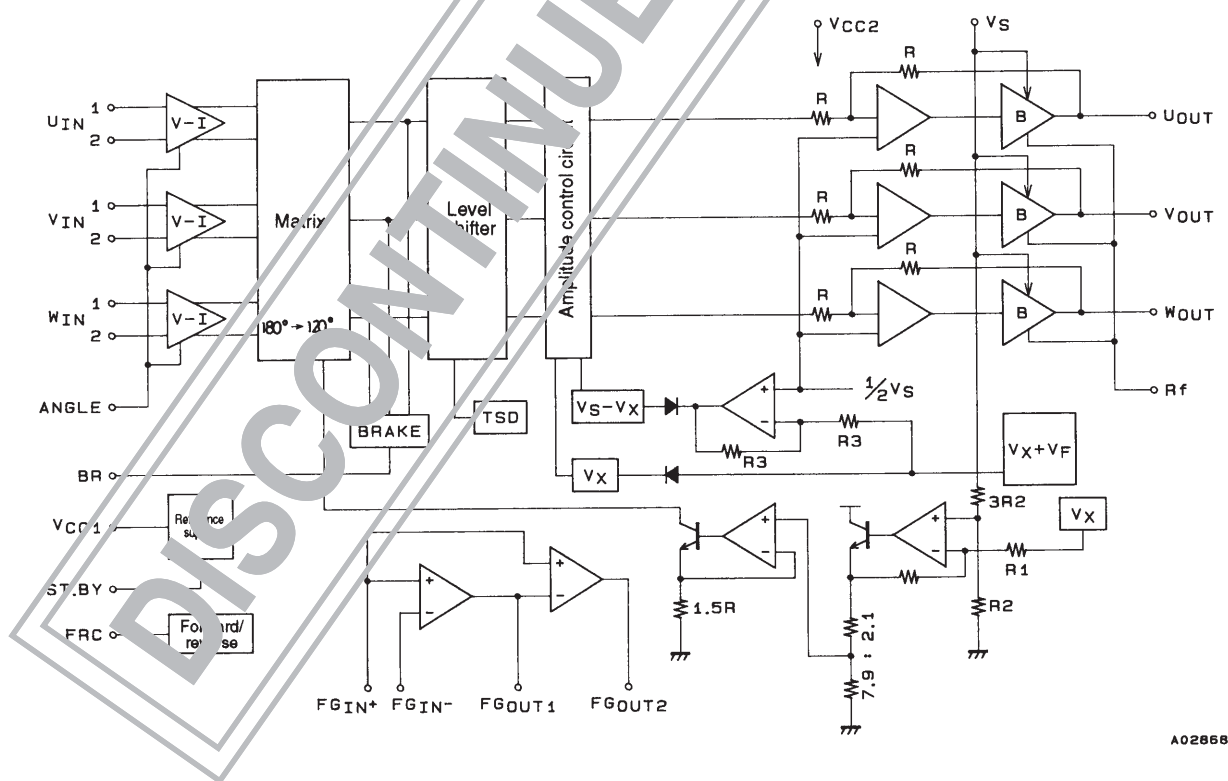
2. These are design target values and are not measured.

The overlap standard is taken as the test standard without change.

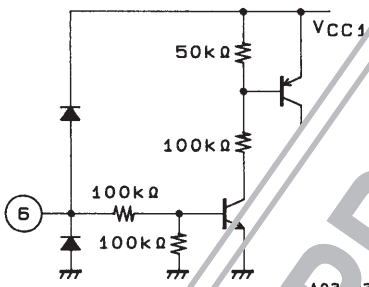
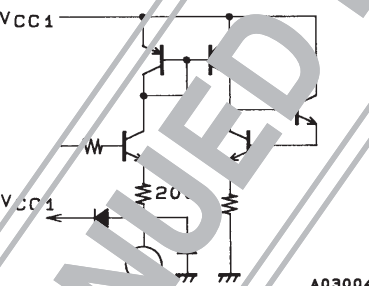
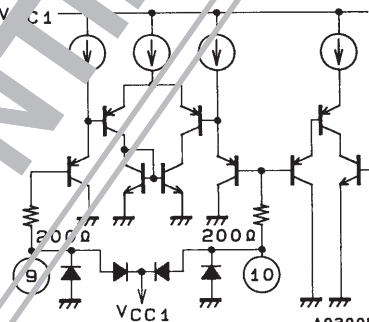
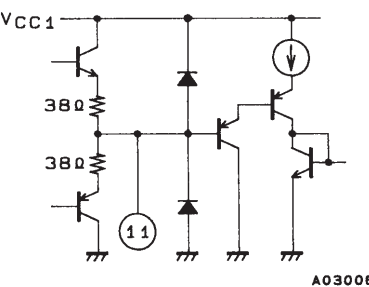
Pin Assignment



Internal Equivalent Circuit Block Diagram



Pin Functions

Pin No.	Symbol	Pin voltage	Equivalent circuit	Function
3	V_S	$< V_{CC2}$		Supply pin that determines the output amplitude. This pin must be set lower than the V_{CC2} voltage.
4	V_{CC2}	4 to 10 V		Power amplifier system power supply for transistors other than those that drive the motor. Power supply voltage for control blocks other than those provided by V_{CC1} .
5	V_{CC1}	4 to 6 V		Power supply voltage for the Hall amplifier, forward/reverse, motor amplifier, and thermal shutdown circuits.
6	ST. BY	H: 2.0 V min L: 0.8 V max (when V_{CC1} is 5 V.)		<p>Pin 6 is turned off by connecting this pin to ground, leaving it open.</p> <p>The current drain is about 0 μA in this mode.</p> <p>Apply 5.0 V or higher for motor drive operation.</p>
7	ANGLE			<p>Connect a resistor between this pin and ground.</p> <p>The Hall input/output gain can be changed by changing the value of this resistor.</p>
9 10	FGin - FGin +	min 0 V max 3.5 V (when V_{CC1} is 5 V.)		FG signal input
11	FGout1			FG amplifier output

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Pin No.	Symbol	Pin voltage	Equivalent circuit	Function
12	FGout2			FG Schmitt amplifier output
14	FRC	H: 2.8 V min L: 1.2 V max (when V_{CC1} is 5 V.)		Motor forward/reverse control Low level: forward (1.2 V or lower when $V_{CC1} = 5$ V) High level: reverse (2.8 V or higher when $V_{CC1} = 5$ V)
15	BR	H: 2.0 V min L: 0.8 V max		Motor stop control Low level: motor drive (0.8 V or lower) High level: Motor stop (2.0 V or higher)
16 17 18 19 20 21	Win2 Win1 Vin2 Vin1 Uin2 Uin1	min 1.4 V max 2.3 V (when V_{CC1} is 5 V.)		W phase Hall element input pin logic High refers to the state where $W_{IN1} > W_{IN2}$ V phase Hall element input pin logic High refers to the state where $V_{IN1} > V_{IN2}$ U phase Hall element input pin logic High refers to the state where $U_{IN1} > U_{IN2}$
22	Rf			Ground for the output transistors
23 24 2	Uout Vout Wout			Outputs
1 13	SUB GND GND			Ground for all circuits other than the output transistor

Truth Table

	Source → sink	Input			Forward/reverse control F/RC
		U	V	W	
1	W phase → V phase V phase → W phase	H	H	L	L
					H
2	W phase → U phase U phase → W phase	H	L	L	L
					H
3	V phase → W phase W phase → V phase	L	L	H	L
					H
4	U phase → V phase V phase → U phase	L	H	L	L
					H
5	V phase → U phase U phase → V phase	H	L	H	L
					H
6	U phase → W phase W phase → U phase	L	H	H	L
					H

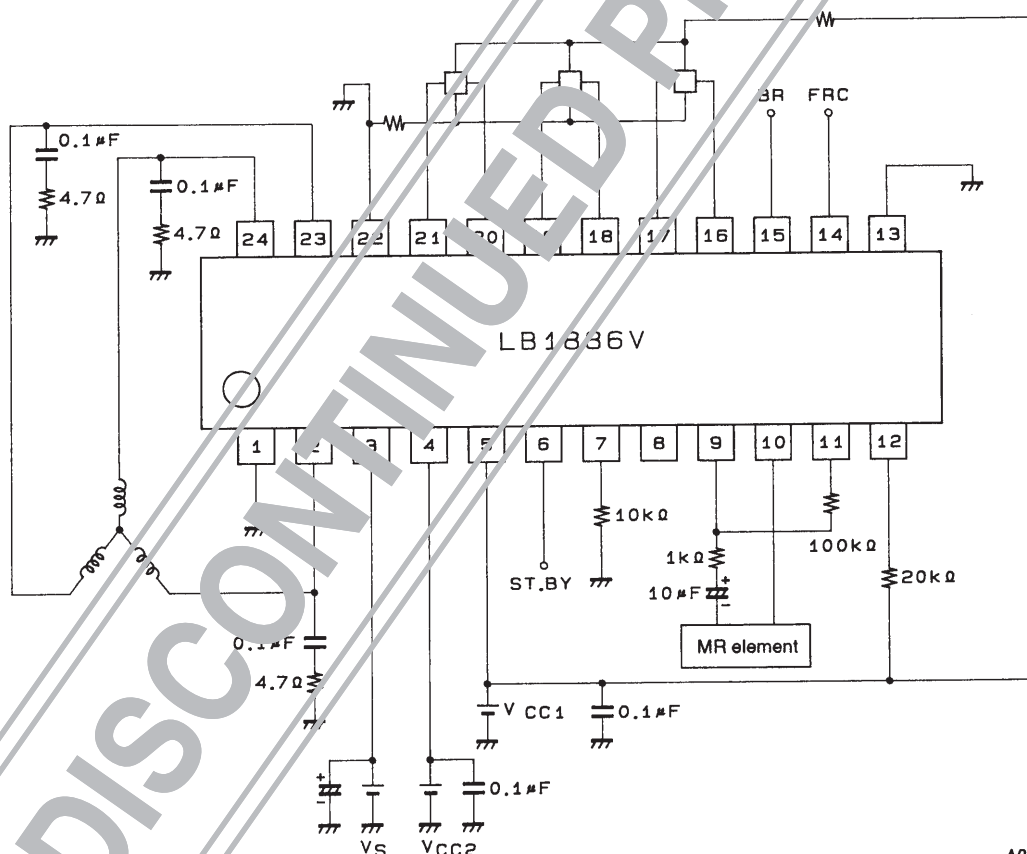
Input high: Indicates that the phase 1 input is at least 0.2 V higher than the phase 2 input for each phase

Input low: Indicates that the phase 1 input is at least 0.2 V lower than the phase 2 input for each phase.

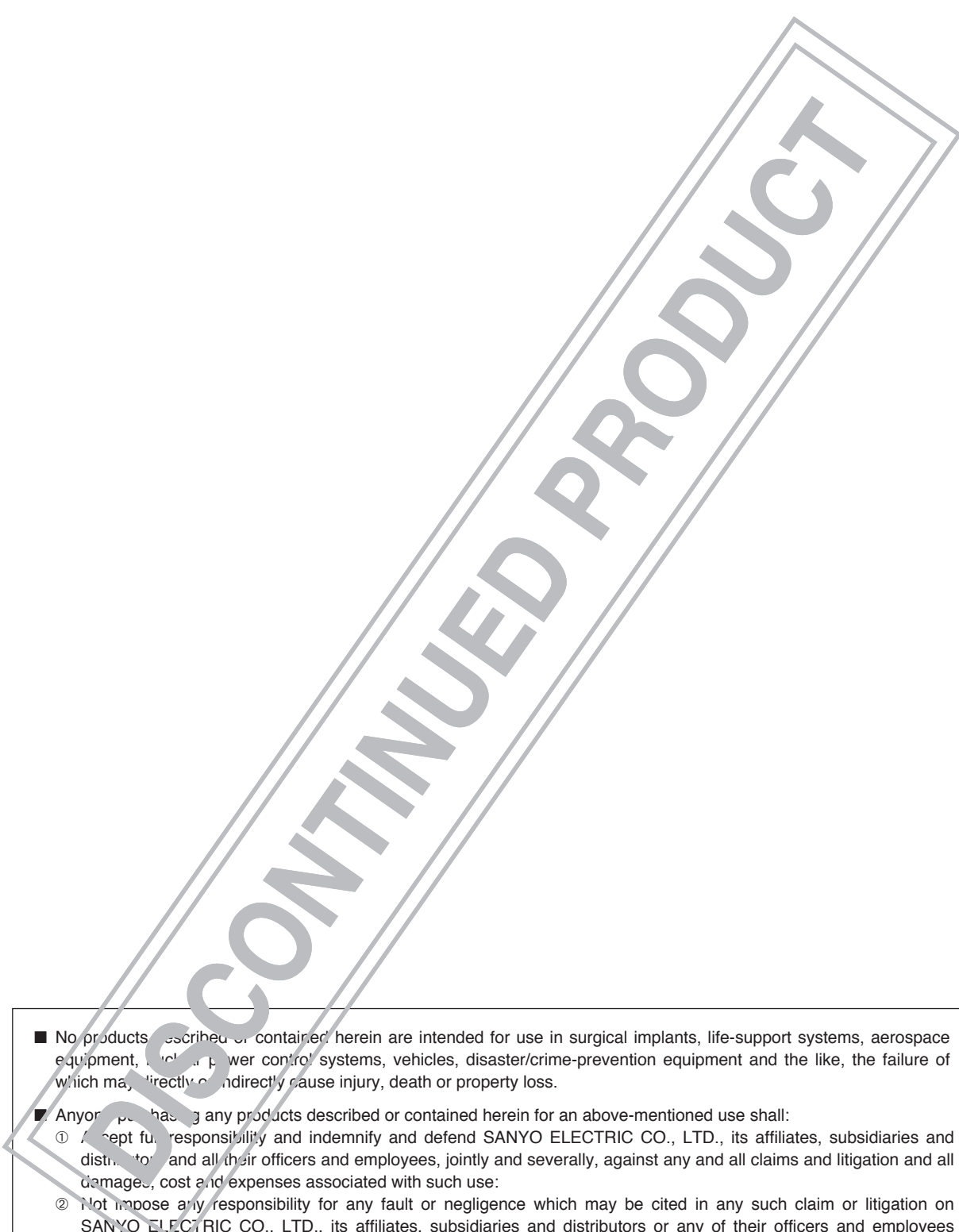
Forward/reverse control: High: 2.8 V to V_{CC1}

Low: 0 V to 1.2 V

Sample Application Circuit



A03012

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